Docket No. 1012-003 Application Serial No. 09/943,859 Substitute Specification under 37 CFR 1.125

ABSTRACT

A hard biased spin-dependent tunneling sensor and manufacturing method therefor is provided having a substrate with a first lead formed thereon. A hard magnet is formed over the first lead and a free layer is formed over the hard magnet. A tunneling barrier layer with a first pinned layer formed thereon is formed over the free layer. A nonmagnetic coupling layer with a second pinned layer formed thereon is formed over the first pinned layer. A pinning layer is formed over the second pinned layer and a second lead is formed over the pinning layer.